

JE8550 (进口芯片)型 PNP 晶体管技术参数说明

参数	型号	JE8550 (T0-92)	单位
P_{tot}		1	W
I_C		-1.5	A
T_j / T_{STG}		-55~+150	°C
BV_{CBO} @ $I_C = -100 \mu A$		≥ -40	V
BV_{CEO} @ $I_C = -1.0mA$		≥ -25	V
BV_{EBO} @ $I_E = -100 \mu A$		≥ -6	V
h_{FE1} @ $V_{CE} = -1V, I_C = -5mA$		≥ 45	-
h_{FE2} @ $V_{CE} = -1V, I_C = -100mA$		85~300	-
h_{FE3} @ $V_{CE} = -1V, I_C = -800mA$		≥ 40	-
I_{CBO} @ $V_{CB} = -35V$		≤ -100	nA
I_{EBO} @ $V_{EB} = -6V$		≤ -100	nA
$V_{CE(sat)}$ @ $I_C = -800mA, I_B = -80mA$		≤ -0.5	V
$V_{BE(sat)}$ @ $I_C = -800mA, I_B = -80mA$		≤ -1.2	V
f_T @ $V_{CE} = -10V, I_C = -50mA$		≥ 100	MHz

TO-92 封装外形图:

